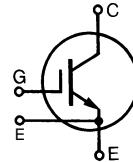
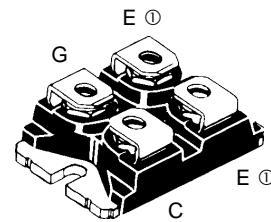


**HiPerFAST™ IGBT****IXGN 200N60B**

$V_{CES}$  = 600 V  
 $I_{C25}$  = 200 A  
 $V_{CE(sat)}$  = 2.1 V



Symbol	Test Conditions	Maximum Ratings	
$V_{CES}$	$T_J$ = 25°C to 150°C	600	V
$V_{CGR}$	$T_J$ = 25°C to 150°C; $R_{GE} = 1\text{ M}\Omega$	600	V
$V_{GES}$	Continuous	±20	V
$V_{GEM}$	Transient	±30	V
$I_{C25}$	$T_c$ = 25°C	200	A
$I_{C90}$	$T_c$ = 90°C	120	A
$I_{CM}$	$T_c$ = 25°C, 1 ms	400	A
<b>SSOA (RBSOA)</b>	$V_{GE} = 15\text{ V}$ , $T_{VJ} = 125^\circ\text{C}$ , $R_G = 2.4\ \Omega$ Clamped inductive load, $L = 30\ \mu\text{H}$	$I_{CM} = 200$ @ 0.8 $V_{CES}$	A
$P_c$	$T_c$ = 25°C	600	W
$T_J$		-55 ... +150	°C
$T_{JM}$		150	°C
$T_{stg}$		-55 ... +150	°C
$V_{ISOL}$	50/60 Hz $I_{ISOL} \leq 1\text{ mA}$	2500 3000	V~
$M_d$	Mounting torque Terminal connection torque (M4)	1.5/13 Nm/lb.in. 1.5/13 Nm/lb.in.	
<b>Weight</b>		30	g

**SOT-227B, miniBLOC**

G = Gate, C = Collector, E = Emitter

① either emitter terminal can be used as Main or Kelvin Emitter

**Features**

- International standard package miniBLOC
- Aluminium nitride isolation
  - high power dissipation
- Isolation voltage 3000 V~
- Very high current, fast switching IGBT
- Low  $V_{CE(sat)}$ 
  - for minimum on-state conduction losses
- MOS Gate turn-on
  - drive simplicity
- Low collector-to-case capacitance (< 50 pF)
- Low package inductance (< 5 nH)
  - easy to drive and to protect

**Applications**

- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switch-mode and resonant-mode power supplies

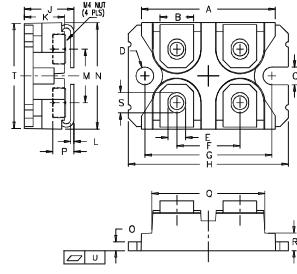
**Advantages**

- Easy to mount with 2 screws
- Space savings
- High power density

Symbol	Test Conditions	Characteristic Values		
		( $T_J = 25^\circ\text{C}$ , unless otherwise specified)	min.	typ.
$BV_{CES}$	$I_c = 1\text{ mA}$ , $V_{GE} = 0\text{ V}$	600		V
$V_{GE(th)}$	$I_c = 1\text{ mA}$ , $V_{CE} = V_{GE}$	2.5		V
$I_{CES}$	$V_{CE} = V_{CES}$ $V_{GE} = 0\text{ V}$	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	200 2	$\mu\text{A}$ mA
$I_{GES}$	$V_{CE} = 0\text{ V}$ , $V_{GE} = \pm 20\text{ V}$		±400	nA
$V_{CE(sat)}$	$I_c = I_{C90}$ , $V_{GE} = 15\text{ V}$		2.1	V

Symbol	Test Conditions	Characteristic Values		
		( $T_J = 25^\circ\text{C}$ , unless otherwise specified)	min.	typ.
$g_{fs}$	$I_C = 60 \text{ A}; V_{CE} = 10 \text{ V},$ Pulse test, $t \leq 300 \mu\text{s}$ , duty cycle $\leq 2 \%$	50	75	S
$C_{ies}$	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$	11000	pF	
$C_{oes}$		680	pF	
$C_{res}$		190	pF	
$Q_g$	$I_C = I_{C90}, V_{GE} = 15 \text{ V}, V_{CE} = 0.5 V_{CES}$	350	nC	
$Q_{ge}$		72	nC	
$Q_{gc}$		131	nC	
$t_{d(on)}$	<b>Inductive load, <math>T_J = 25^\circ\text{C}</math></b> $I_C = 100\text{A}, V_{GE} = 15 \text{ V}$ $V_{CE} = 0.8 V_{CES}, R_G = R_{off} = 2.4 \Omega$ Remarks: Switching times may increase for $V_{CE}$ (Clamp) $> 0.8 \cdot V_{CES}$ , higher $T_J$ or increased $R_G$	60	ns	
$t_{ri}$		45	ns	
$E_{on}$		2.4	mJ	
$t_{d(off)}$		200	360	ns
$t_{ri}$		160	280	ns
$E_{off}$		5.5	9.6	mJ
$t_{d(on)}$	<b>Inductive load, <math>T_J = 125^\circ\text{C}</math></b> $I_C = 100\text{A}, V_{GE} = 15 \text{ V}$ $V_{CE} = 0.8 V_{CES}, R_G = R_{off} = 2.4 \Omega$ Remarks: Switching times may increase for $V_{CE}$ (Clamp) $> 0.8 \cdot V_{CES}$ , higher $T_J$ or increased $R_G$	60	ns	
$t_{ri}$		60	ns	
$E_{on}$		4.8	mJ	
$t_{d(off)}$		290	ns	
$t_{ri}$		250	ns	
$E_{off}$		8.7	mJ	
$R_{thJC}$			0.21	K/W
$R_{thCK}$		0.05		K/W

## miniBLOC, SOT-227 B



M4 screws (4x) supplied

Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	31.50	31.88	1.240	1.255
B	7.80	8.20	0.307	0.323
C	4.09	4.29	0.161	0.169
D	4.09	4.29	0.161	0.169
E	4.09	4.29	0.161	0.169
F	14.91	15.11	0.587	0.595
G	30.12	30.30	1.186	1.193
H	38.00	38.23	1.496	1.505
J	11.68	12.22	0.460	0.481
K	8.92	9.60	0.351	0.378
L	0.76	0.84	0.030	0.033
M	12.60	12.85	0.496	0.506
N	25.15	25.42	0.990	1.001
O	1.98	2.13	0.078	0.084
P	4.95	5.97	0.195	0.235
Q	26.54	26.90	1.045	1.059
R	3.94	4.42	0.155	0.174
S	4.72	4.85	0.186	0.191
T	24.59	25.07	0.968	0.987
U	-0.05	0.1	-0.002	0.004